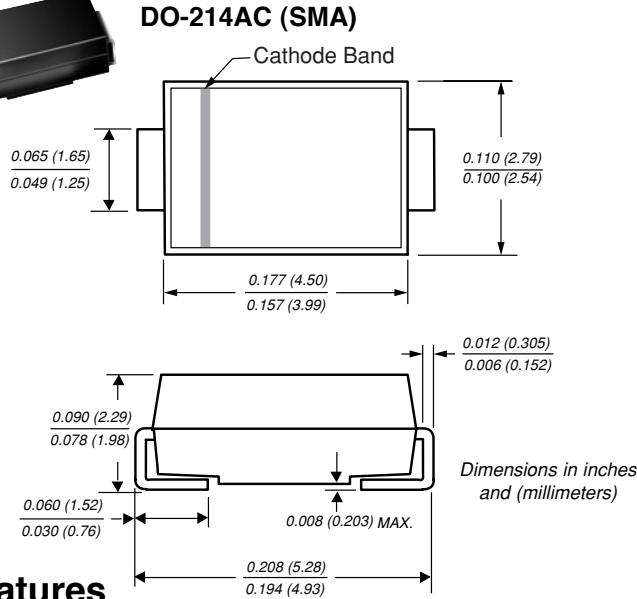


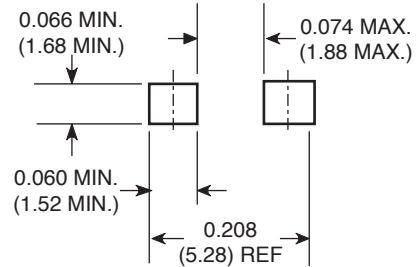


# High-Current Density Surface Mount Schottky Rectifier

Reverse Voltage 30 & 40 V  
Forward Current 2.0 A



## Mounting Pad Layout



## Features

- Low power loss, high efficiency
- Low profile surface mount package
- Built-in strain relief
- For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0

## Mechanical Data

**Case:** JEDEC DO-214AC molded plastic body  
**Terminals:** Solder plated, solderable per MIL-STD750, Method 2026  
 High temperature soldering guaranteed: 250°C/10 seconds at terminals  
**Polarity:** Color band denotes cathode end  
**Weight:** 0.002 ounce, 0.064 gram

## Maximum Ratings and Thermal Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Symbol	SSA23L	SSA24	Unit
Device marking code		23L	S24	V
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	30	40	V
Maximum RMS voltage	V <sub>RMS</sub>	21	28	V
Maximum DC blocking voltage	V <sub>DC</sub>	30	40	V
Maximum average forward rectified current at T <sub>L</sub> (See Fig. 1)	I <sub>F(AV)</sub>	2.0		A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	60		A
Non-repetitive avalanche energy at T <sub>A</sub> = 25°C, I <sub>AS</sub> = 1.5A, L = 10mH	E <sub>AS</sub>	11.25		mJ
Typical thermal resistance <sup>(2)</sup>	R <sub>θJA</sub> R <sub>θJL</sub>	110 28		°C/W
Voltage rate of change (rated V <sub>R</sub> )	dv/dt	10,000		V/μs
Operating junction temperature range	T <sub>J</sub>	-65 to + 150		°C
Storage temperature range	T <sub>STG</sub>	-65 to + 150		°C

## Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Typ.	Max.	Typ.	Max.	Unit
Maximum instantaneous forward voltage at 2.0A <sup>(1)</sup>	V <sub>F</sub>	0.43	0.45	0.45	0.49	V
		0.32	0.38	0.36	0.42	
Maximum DC reverse current at rated DC blocking voltage <sup>(1)</sup>	I <sub>R</sub>	–	0.5	–	0.2	mA
		15	25	12	20	

**Notes:** (1) Pulse test: 300μs pulse width, 1% duty cycle  
 (2) Aluminum substrate mounted

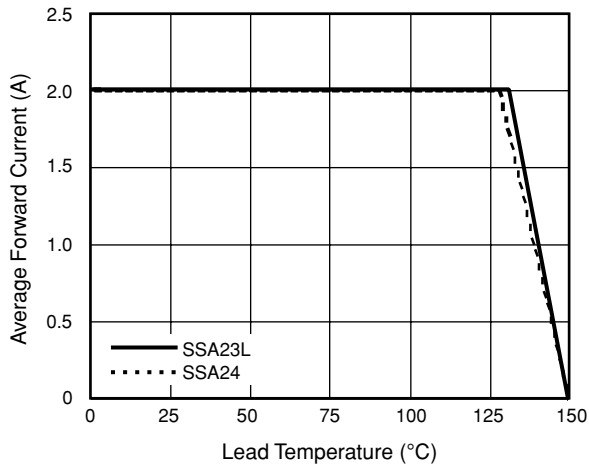
# SSA23L and SSA24



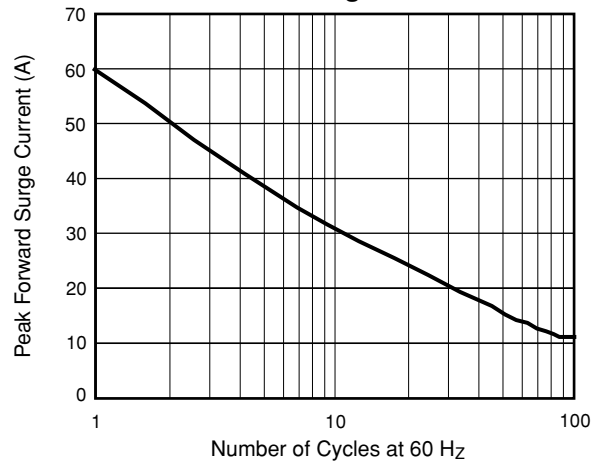
Vishay Semiconductors  
formerly General Semiconductor

## Ratings and Characteristic Curves ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

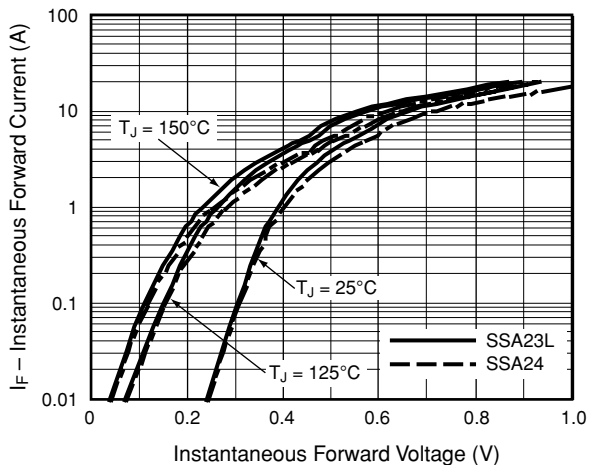
**Fig. 1 – Forward Current Derating Curve**



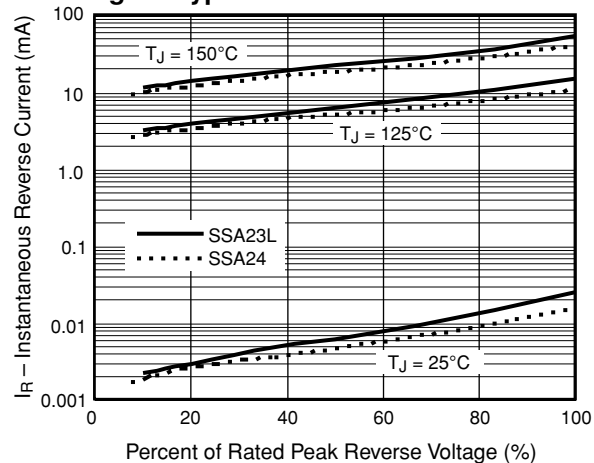
**Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current**



**Fig. 3 - Typical Instantaneous Forward Characteristics**



**Fig. 4 - Typical Reverse Characteristics**



**Fig. 5 - Typical Junction Capacitance**

